

UMZ7N

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# General purpose transistor (dual transistors)

# EMZ7 / UMZ7N

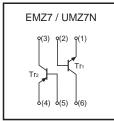
# Features

- 1) Both a 2SA2018 chip and 2SC5585 chip in a EMT or UMT package.
- 2) Mounting possible with EMT3 or UMT3
- automatic mounting machines.
- 3) Transistor elements are independent, eliminating interference.
- 4) Mounting cost and area can be cut in half.
- 5) Low VCE(sat)

# Structure

NPN / PNP epitaxial planar silicon transistor

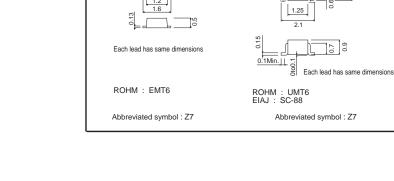
# Inner circuit



# • Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Lin	nits	Unit
Farameter	Symbol	Tr <sub>1</sub>	Tr <sub>2</sub>	Unit
Collector-base voltage	Vсво	15	-15	V
Collector-emitter voltage	Vceo	12	-12	V
Emitter-base voltage	Vево	6	-6	V
Collector current	lc	500	-500	mA
	Іср	1	-1	А
Collector power dissipation	Pc	150(T	OTAL)	mW *1
Junction temperature	Tj	15	50	°C
Storage temperature	Tstg	–55 to	o +150	°C

\*1 120mW per element must not be exceeded.



1.0

•Dimensions (Unit : mm)

EMZ7

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# • Electrical characteristics (Ta=25°C) Tr1 (NPN)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	15	_	-	V	Ic=10μA
Collector-emitter breakdown voltage	BVCEO	12	_	-	V	Ic=1mA
Emitter-base breakdown voltage	ВУево	6	_	-	V	Iε=10μA
Collector cutoff current	Ісво	-	-	0.1	μΑ	Vcb=15V
Emitter cutoff current	Іево	-	_	0.1	μΑ	VEB=6V
Collector-emitter saturation voltage	VCE(sat)	-	90	250	mV	Ic/IB=200mA/10mA
DC current transfer ratio	hfe	270	_	680	-	Vce/Ic=2V/10mA
Transition frequency	fт	-	320	-	MHz	Vce=2V, Ic=-10mA, f=100MHz
Output capacitance	Cob	-	7.5	_	pF	Vcb=10V, IE=0A, f=1MHz

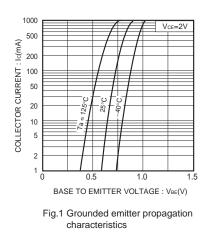
# Tr<sub>2</sub> (PNP)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	-15	-	-	V	Ic=-10μA
Collector-emitter breakdown voltage	BVCEO	-12	-	-	V	Ic=-1mA
Emitter-base breakdown voltage	ВVево	-6	-	-	V	Iε=-10μA
Collector cutoff current	Ісво	-	-	-0.1	μΑ	Vcb=-15V
Emitter cutoff current	Іево	-	-	-0.1	μΑ	VEB=-6V
Collector-emitter saturation voltage	VCE(sat)	-	-100	-250	mV	Ic/I <sub>B</sub> =-200mA/-10mA
DC current transfer ratio	hfe	270	-	680	-	Vce/lc=-2V/-10mA
Transition frequency	fт	-	260	-	MHz	Vce=-2V, Ic=10mA, f=100MHz
Output capacitance	Cob	_	6.5	_	pF	Vcb=-10V, Ie=0A, f=1MHz

# Packaging specifications

	Packaging type	Тарі	ng
	Code	TR	T2R
Part No.	Basic ordering unit (pieces)	3000	8000
UMZ7N		0	-
EMZ7		-	0

# •Electrical characteristic curves Tr1 (NPN)



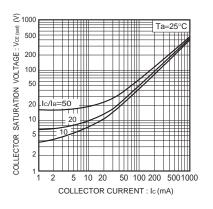


Fig.4 Collector-emitter saturation voltage vs. collector current ( II )

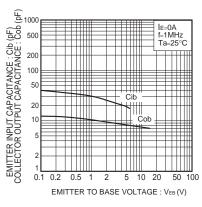
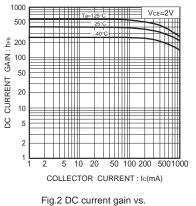


Fig.7 Collector output capacitance vs collector-base voltage Emitter input capacitance vs emitter-base voltage



g.2 DC current gain vs. collector current

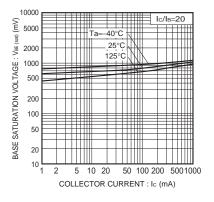
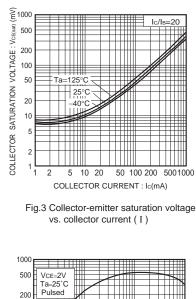
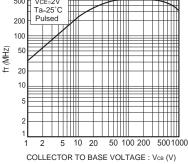
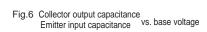


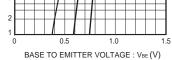
Fig.5 Base-emitter saturation voltage vs. collector current







# Tr2 (PNP)



Vcr=2V

Fig.8 Grounded emitter propagation characteristics

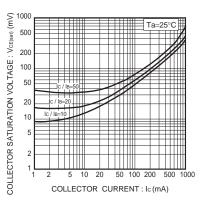
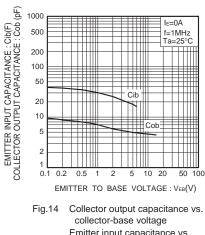
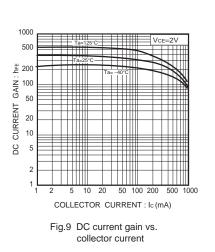


Fig.11 Collector-emitter saturation voltage vs. collector current



Emitter input capacitance vs. emitter-base voltage



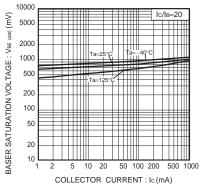


Fig.12 Base-emitter saturation voltage vs. collector current

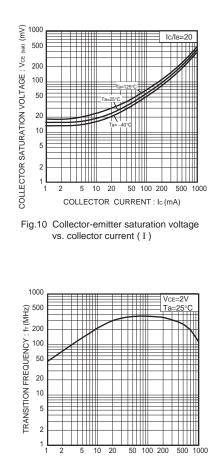


Fig.13 Gain bandwidth product vs. emitter current

EMITTER CURRENT : Ic (mA)

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